

Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

Claim 1 (original): A semiconductor device comprising:
at least one thin film transistor having an active layer comprising crystalline semiconductor film comprising silicon;
at least one circuit comprising said thin film transistor formed on a substrate having an insulating surface;
a plurality of wiring lines formed into said circuit; and
a plurality of wiring lines connected with said circuit,
wherein at least part of at least one of said wiring lines is electrically connected in parallel with an auxiliary wiring line through an interlayer insulating film.

Claims 2-9 (canceled)